NSN 5961-01-320-0004

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-320-0004 **Inclosure Material:** Metal all semiconductor device diode **Function For Which Designed:** Varactor diode **Internal Configuration:** Junction contact all semiconductor device diode **Internal Junction Configuration:** Pn all semiconductor device diode **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 85.0 degrees celsius ambient air all semiconductor device diode Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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